

Minimizing test mass thermal noise with crystalline coatings



Garrett D. Cole

Crystalline Mirror Solutions LLC & GmbH May 27, 2016





- Brief introduction to Brownian thermal noise
 - background on the problem and its consequences
- Overview of substrate-transferred crystalline coatings
 - timeline of the technological development and current status
- Prospects for realizing GW-relevant crystalline coatings
 - discussion on the next steps for developing low-loss GW optics

Thermal (Brownian) Noise





- Precision interferometers are now limited by Brownian noise
 - from cm-scale reference cavities to km-length GW detectors

Ultimate Limits of Cavity Performance



Brownian Noise

Fluctuating Mirror



Mechanical fluctuations set the ultimate stability limit

Brownian Noise Consequences





- Dielectric optical coatings (Ta₂O₅/SiO₂) are a major limitation
 - from LSC studies by Crooks, Harry, Penn, etc. Ta₂O₅ is the culprit
 - loss angle has been reduced by a factor of ~2 over the last decade
- Crystalline coatings represent an exciting alternative solution
 - simultaneous achievement of high optical and mechanical quality

Kessler, et al. Nature Photonics 2012 | Harry, Bodiya, DeSalvo eds., Cambridge Univ. Press 2012

Ion Beam Sputtered Films





- Multilayer of amorphous thin films via ion beam sputtering (IBS)
- Phenomenal optical properties: high R, low absorption and scatter
- Flexible choice of substrates assuming excellent surface quality
 - super-polished SiO₂, Si, ULE, sapphire, etc.

Lattice-Matched Epitaxial Structures





Epitaxial Coating Details



- AlGaAs multilayer with varying Al content for index contrast
 - high index layers consist of binary GaAs thin films
 - 8% Ga incorporated in low index AlGaAs layers to slow oxidation in ambient
- Potential for high reflectivity from ~900 nm \rightarrow 5+ μm
 - peak performance in NIR
- High quality epitaxy requires a lattice matched substrate
 - same crystalline symmetry
 - minimal deviation of lattice parameter (atomic spacing)



- AlGaAs multilayer with varying Al content for index contrast
 - high index layers consist of binary GaAs thin films

Epitaxial Coating Details

- 8% Ga incorporated in low index AlGaAs layers to slow oxidation in ambient
- Potential for high reflectivity from ~900 nm \rightarrow 5+ μm
 - peak performance in NIR
- High quality epitaxy requires a lattice matched substrate
 - same crystalline symmetry
 - minimal deviation of lattice parameter (atomic spacing)







Alternative Technology: GaP/Al_xGa_{1-x}P





- Epitaxial DBR directly deposited on silicon (Stanford/UWS)
 - interference coatings based on GaP/Al_{0.9}Ga_{0.1}P epitaxial multilayers
- Proof-of-concept yields promising cryo loss angles (~1×10⁻⁵)
 - reflectivity of 83% at RT (as expected), ~2% absorption (first pass)

Why Choose Crystalline Reflectors?



- Current deposition techniques make imperfect thin film materials
- Crystalline films seem to have inherently lower defect densities
 - epitaxy apparently yields better crystals than IBS yields glasses

VOLUME 59, NUMBER 18

PHYSICAL REVIEW LETTERS

2 NOVEMBER 1987

Two-Level Systems Observed in the Mechanical Properties of Single-Crystal Silicon at Low Temperatures

R. N. Kleiman, G. Agnolet, ^(a) and D. J. Bishop AT&T Bell Laboratories, Murray Hill, New Jersey 07974 (Received 8 June 1987)

Using the high-Q mechanical-oscillator technique we have measured the sound velocity and mechanical dissipation of high-purity single-crystal silicon as functions of temperature (0.005-4.2 K), frequency (0.6-6.0 kHz), and strain amplitude ($10^{-5}-10^{-8}$). In the mechanical properties we find a surprisingly strong temperature dependence with the same qualitative behavior for silicon as for vitreous silica. This implies a density of two-level systems only 2 orders of magnitude lower for silicon than amorphous silica.





- Brief introduction to Brownian thermal noise
 - background on the problem and its consequences
- Overview of substrate-transferred crystalline coatings
 - timeline of the technological development and current status
- Prospects for realizing GW-relevant crystalline coatings
 - discussion on the next steps for developing low-loss GW optics



We offer an entirely unique technology for precision laser optics

- Applications span fundamental R&D + emerging industrial uses
 - cutting-edge research efforts in spectroscopy and metrology
 - advanced industrial applications in manufacturing and sensing







iii) cavity employed for laser stabilization





- **2007** GaAs/Al_xGa_{1-x}As micro-resonator development begins at LLNL
- **2008** moved to Vienna (IQOQI) to continue optomechanics research, first contact with Gregg Harry, Nergis Mavalvala, & Achim Peters
- **2009** (September) initial thoughts on transferred coatings
- 2010 (July) seminar @ MIT, introduced transferred coating concept
- 2011 first time attending GWADW (Elba) revisited bonding idea
- 2012 first "real" mirrors fabricated and presented at GWADW Hawaii
- 2012 (December) JILA direct thermal noise measurements completed
- 2013 significant external interest, CMS GmbH & LLC incorporated
- 2014 return to US to setup manufacturing, first products shipped
- **2015** finesse reaches 200,000, sub-ppm absorption verified at a center wavelength of 1064 nm (with SPTS), bonding area up to 10 cm
- 2016 finesse of ~360,000 measured, first tests of mid-IR optics

Mechanical Loss of Optical Coatings





free-standing Ta_2O_5/SiO_2 HR coating Reflectivity >0.9999, Q ~ 2000 – 6000 loss angle (Q⁻¹) similar to LIGO data

S. Gröblacher, S. Gigan, H. Böhm, A. Zeilinger, M. Aspelmeyer, Eur. Phys. Lett. 81, 54003 (2008)



free-standing epitaxial AlGaAs DBR Reflectivity >0.9999, Q ~ $2 \times 10^4 - 2 \times 10^5$ Significantly reduced damping, similar R

a) Cole, et al., Appl. Phys. Lett. 92, 261108 (2008)b) G. D. Cole, Proc. SPIE. 8458–07 (2012)

Spin-Off of Quantum Optomechanics



Epitaxial AlGaAs micro resonators





free-standing epitaxial AlGaAs

reflectivity >0.9999 (ppm losses) loss angle $< 2 \times 10^{-5}$ to $< 5 \times 10^{-6}$

a) Cole, et al., *Appl. Phys. Lett.* 92 (2008)
b) Cole, *Proc. SPIE.* 8458–07 (2012)
c) Aspelmeyer et al., *RMP* 86, 1391 (2014)

Spin-Off of Quantum Optomechanics



Epitaxial AlGaAs micro resonators



free-standing epitaxial AlGaAs reflectivity >0.9999 (ppm losses)

loss angle $< 2 \times 10^{-5}$ to $< 5 \times 10^{-6}$

a) Cole, et al., *Appl. Phys. Lett.* 92 (2008)
b) Cole, *Proc. SPIE.* 8458–07 (2012)
c) Aspelmeyer et al., *RMP* 86, 1391 (2014)

Substrate-transferred crystalline coatings



Spin-Off of Quantum Optomechanics



Epitaxial AlGaAs micro resonators



Substrate-transferred crystalline coatings



free-standing epitaxial AlGaAs reflectivity >0.9999 (ppm losses) loss angle <2 × 10⁻⁵ to <5 × 10⁻⁶

a) Cole, et al., *Appl. Phys. Lett.* 92 (2008)
b) Cole, *Proc. SPIE.* 8458–07 (2012)
c) Aspelmeyer et al., *RMP* 86, 1391 (2014)



Fixed-Spacer Reference Cavity



- Zerodur spacer with optically contacted AlGaAs-on-silica mirrors
 - short cavity length to accentuate mirror thermal noise effects
- Cavity mounted in a temperature controlled vacuum chamber
 - eliminate index variations and spacer thermal fluctuations
 - nodal support to minimize acceleration sensitivity
- Prototype and test-bed for optomechanical performance verification
 - cavity used for the construction of a stabilized laser at 1064 nm





Fixed-Spacer Reference Cavity



- Zerodur spacer with optically contacted AlGaAs-on-silica mirrors
 - short cavity length to accentuate mirror thermal noise effects
- Cavity mounted in a temperature controlled vacuum chamber
 - eliminate index variations and spacer thermal fluctuations
 - nodal support to minimize acceleration sensitivity
- Prototype and test-bed for optomechanical performance verification
 - cavity used for the construction of a stabilized laser at 1064 nm





Reduced Brownian Noise





- Tenfold reduction in mechanical dissipation at room temperature
- Further 10 × improvement upon cooling to cryogenic temperatures

Sub-ppm NIR Absorption





- Red HeNe probe in PCI system limits minimum absorption value
 - the use of a transparent near-IR probe is now being investigated
- Probe-power dependent measurements yield sub-ppm absorption

Measurements by Dr. Alexei Alexandrovski, SPTS Pahoa, HI

Optimized Coating Process





- Epitaxial growth process has been optimized for low defect density
 - full effusion cells, clean chamber walls, optimized subs. temperature
- Microfabrication-based transfer process also optimized (cleaning)
 - consistent, position-independent losses as low as 3 ppm now possible

Measurements by W. Zhang and L. Sonderhouse, JILA, at SLS (Mark Notcutt), Boulder, CO

JILA 25-cm Long RT Reference Cavity





JILA 25-cm Long RT Reference Cavity





- "Cutout" spacer design for minimizing acceleration sensitivity
- Cavity will ultimately be used for fiber stabilization system @ JILA

300,000 Finesse





G. D. Cole, et al., pre-print arXiv:1604.00065 (2016)

Cavity Birefringence





- Crystalline coatings yield a relatively strong cavity birefringence
 - $\sim 1-5 \times 10^{-3}$ compared with 10^{-4} to 10^{-6} for amorphous multilayers
- Polarization eigenmodes are well resolved, splitting >> linewidth
 - 220 kHz splitting compared with 2 kHz linewidth for 25-cm long spacer

G. D. Cole, et al., pre-print arXiv:1604.00065 (2016)



Substrate-transferred crystalline coatings simultaneously exhibit excellent optical and mechanical quality

- Damping reduction of 10-100 × compared with IBS films
 - IBS-deposited Ta_2O_5/SiO_2 : typical Q ~3000 ($\phi_{IBS} \approx 2.4 \times 10^{-4}$)
 - AlGaAs room temperature Q-value of 4×10^4 ($\phi_{RT} \approx 2 \times 10^{-5}$)
 - AlGaAs cryogenic performance: $Q > 1 \times 10^5 (\phi_{min} \approx 4.5 \times 10^{-6})$
- Minimal scattering loss and optical absorption
 - absorption verified at < 1 ppm (< 0.01 cm⁻¹ at 1064 nm)
 - RMS micro-roughness of 1.3 Å RMS (< 3 ppm at 1064 nm)
- Excess losses (S+A) down to levels < 5 ppm</p>
 - measured finesse of $>2 \times 10^5$ at 1064, 1397 and 1550 nm





- Brief introduction to Brownian thermal noise
 - background on the problem and its consequences
- Overview of substrate-transferred crystalline coatings
 timeline of the technological development and current status
- Prospects for realizing GW-relevant crystalline coatings
 - discussion on the next steps for developing low-loss GW optics

Challenges in Implementation



- Minimizing thermo-optic noise in crystalline coatings
 - large thermal expansion coefficient (thermo-elastic noise)
 - large thermo-refractive coefficient (thermo-refractive noise)
- Substrates are a major question mark, 2 paths forward:
 - Homoepitaxy (AlGaAs on GaAs): highest material quality
 - maximum wafer size (200 mm) is a serious limitation
 - solution: ~\$5M investment for >30-cm Ø GaAs crystal growth
 - Heteroepitaxy (AlGaAs on Si/Ge): wafers up to 450 mm Ø
 - background doping (i.e. interdiffusion of Ge) must be minimized
 - surface roughness needs to be improved (nm scale at this point)
 - verified mechanical loss angle of 8×10⁻⁶ (5 K) w/ T. Corbitt
 - solution: intensive materials development effort required

T. Chalermsongsak, et al., Metrologia, vol. 53, 860 (2016)



• Minimizing thermo-optic noise in crystalline coatings

- large thermal expansion coefficient (thermo-elastic noise)
- large thermo-refractive coefficient (thermo-refractive noise)
- Substrates are a major question mark, 2 paths forward:
 - Homoepitaxy (AlGaAs on GaAs): highest material quality
 - maximum wafer size (200 mm) is a serious limitation
 - solution: ~\$5M investment for >30-cm Ø GaAs crystal growth

Heteroepitaxy (AlGaAs on Si/Ge): wafers up to 450 mm Ø

- background doping (i.e. interdiffusion of Ge) must be minimized
- surface roughness needs to be improved (nm scale at this point)
- verified mechanical loss angle of 8×10⁻⁶ (5 K) w/ T. Corbitt
- solution: intensive materials development effort required

• Development of custom tools, both growth and bonding

Scalable Production Technique





- Substrate-transfer process leverages existing infrastructure
 - high-uniformity epitaxial growth on large-diameter substrates
 - void-free direct bonding of crystalline semiconductors
 - commercial tools available for arbitrary mirror sizes

Exploit Semiconductor Infrastructure





- Production MBE reactors for microwave electronics
 - 7 x 150-mm or 4 x 200-mm wafers (Veeco GEN2k/Riber 7000)
- Direct bonding systems for SOI wafer production
 - industrial tools capable of bonding 450-mm diam. wafers

* Photo credit: Bob Yanka, RFMD; Veeco GEN2000 multi-wafer production MBE system

First Test: AEI "SQL Optics" Effort





- Goal: produce high-performance large-area crystalline coatings
 - must realize defect (i.e. void and particle free) direct bonding
 - ensure the highest optical quality, enabling ppm-level optical losses
- Can we achieve a sufficiently high yield to produce such optics?

Large-Area Prototype Optics





Coating Disc Definition





Partially Processed Coatings





First Test Parts, April 13, 2016









Crystalline coatings are a viable option for large-area low-noise optics, though a lot of work remains to be done

- Properties must be studied against LIGO specifications
 - wavefront error of large-area coatings must be studied
 - the same samples can be used to verify optical (and potentially mechanical) performance of our coatings
- Further scaling investigations must be initiated
 - a staged approach involving increasingly larger optics should be started as soon as possible (150 or 200 mm diameter parts?)
- GaAs substrate development will have to start soon
 - crystal growth manufacturers need ~2-3 year head-start
 - can be co-funded via semiconductor microelectronics industry

The Current CMS Team



























Thank You For Your Attention!



